



**CHENMKO ENTERPRISE CO.,LTD**

**SURFACE MOUNT  
Dual Digital Silicon Transistor**

**VOLTAGE 50 Volts CURRENT 100 mAmpere**

*Lead free devices*

**CHIMD8PT**

**APPLICATION**

- \* Switching circuit, Inverter, Interface circuit, Driver circuit.

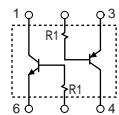
**FEATURE**

- \* Small surface mounting type. (SC-74/SOT-457)
- \* High current gain.
- \* Suitable for high packing density.
- \* Low collector-emitter saturation.
- \* High saturation current capability.
- \* Both the CHDTA144T & CHDTC144T in one package.
- \* Built in bias resistor( $R_1=47\text{k}\Omega$ , Typ. )

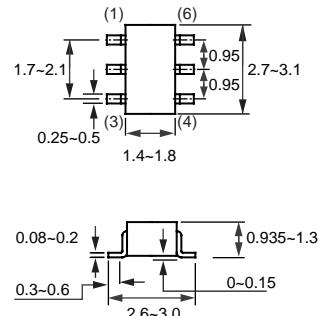


**SC-74/SOT-457**

**CIRCUIT**



Dimensions in millimeters



**SC-74/SOT-457**

**CHDTA144T LIMITING VALUES**

In accordance with the Absolute Maximum Rating System .

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$V_{CBO}$	Collector-Base voltage		-50	V
$V_{CEO}$	Collector-Emitter voltage		-50	V
$V_{EBO}$	Emitter-Base voltage		-5	V
$I_c$	Collector current		-100	mA
$P_c$	Collector Power dissipation	$T_{amb} \leq 25^\circ\text{C}$ , Note 1	300	mW
$T_{STG}$	Storage temperature		-55 +150	°C
$T_J$	Junction temperature		-55 +150	°C
$R_{\theta J-S}$	Thermal resistance , Note 1	junction - soldering point	140	°C/W

**Note**

- Transistor mounted on an FR4 printed-circuit board.

### CHDTC144T LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base voltage		50	V
V <sub>C EO</sub>	Collector-Emitter voltage		50	V
V <sub>EBO</sub>	Emitter-Base voltage		5	V
I <sub>C</sub> (Max.)	Collector current		100	mA
P <sub>D</sub>	Power dissipation	T <sub>amb</sub> ≤ 25 °C, Note 1	300	mW
T <sub>STG</sub>	Storage temperature		-55 +150	°C
T <sub>J</sub>	Junction temperature		-55 +150	°C
R <sub>θJ-S</sub>	Thermal resistance , Note 1	junction - soldering point	140	°C/W

#### Note

- Transistor mounted on an FR4 printed-circuit board.

### CHDTA144T CHARACTERISTICS

T<sub>amb</sub> = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
BV <sub>CBO</sub>	Collector-Base breakdown voltage	I <sub>C</sub> = -50uA	-50.0	—	—	V
BV <sub>C EO</sub>	Collector-Emitter breakdown voltage	I <sub>C</sub> = -1mA	-50.0	—	—	V
BV <sub>EBO</sub>	Emitter-Base breakdown voltage	I <sub>E</sub> = -50uA	-5.0	—	—	V
V <sub>C E(sat)</sub>	Collector-Emitter Saturation voltage	I <sub>C</sub> = -5mA; I <sub>B</sub> = -0.5mA	—	—	-0.3	V
I <sub>CBO</sub>	Collector-Base current	V <sub>CB</sub> = -50V	—	—	-0.5	uA
I <sub>EBO</sub>	Emitter-Base current	V <sub>EB</sub> = -4V	—	—	-0.5	uA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = -1mA; V <sub>C E</sub> = -5.0V	100	250	600	
R <sub>1</sub>	Input resistor		32.9	47	61.1	KΩ
f <sub>T</sub>	Transition frequency	I <sub>E</sub> =5mA, V <sub>C E</sub> = -10.0V f=100MHz	—	250	—	MHz

#### Note

- Pulse test: tp≤300uS; δ≤0.02.

### CHDTC144T CHARACTERISTICS

T<sub>amb</sub> = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
BV <sub>CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> =50uA	50	—	—	V
BV <sub>C EO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> =1.0mA	50	—	—	V
BV <sub>EBO</sub>	Emitter-base breakdown voltage	I <sub>E</sub> =50uA	5.0	—	—	V
I <sub>CBO</sub>	Collector cutoff current	V <sub>CB</sub> =50V	—	—	0.5	uA
I <sub>EBO</sub>	Emitter cutoff current	V <sub>EB</sub> =4V	—	—	0.5	uA
V <sub>C E(sat)</sub>	Collector-emitter saturation voltage	I <sub>C</sub> /I <sub>B</sub> =5mA/0.5mA	—	—	0.3	V
h <sub>FE</sub>	DC current gain	I <sub>C</sub> =1mA; V <sub>C E</sub> =5.0V	100	250	600	
R <sub>1</sub>	Input resistor		32.9	47	61.1	KΩ
f <sub>T</sub>	Transition frequency	I <sub>C</sub> =5mA, V <sub>C E</sub> =10.0V f=100MHz	—	250	—	MHz

#### Note

- Pulse test: tp≤300uS; δ≤0.02.

## RATING CHARACTERISTIC CURVES ( CHIMD8PT)

### CHDTA144T Typical Electrical Characteristics

Fig.1 DC current gain vs. collector current

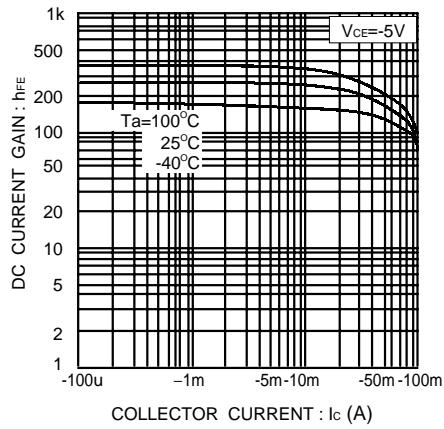
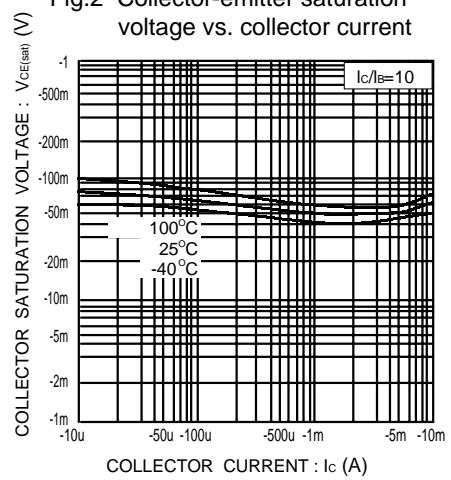


Fig.2 Collector-emitter saturation voltage vs. collector current



## RATING CHARACTERISTIC CURVES ( CHIMD8PT)

### CHDTC144T Typical Electrical Characteristics

Fig.1 DC current gain vs. collector current

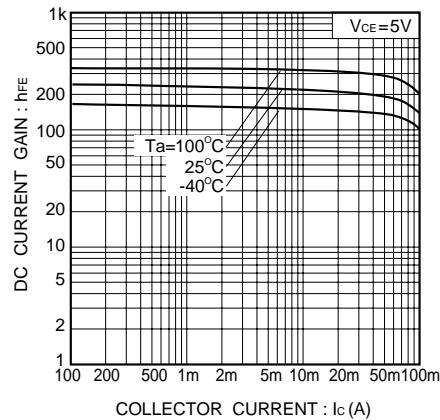


Fig.2 Collector-emitter voltage vs. collector current

